

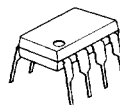
DUAL GENERAL PURPOSE OPERATIONAL AMPLIFIER

■ GENERAL DESCRIPTION

The NJM1458 is a monolithic pair of Internally Compensated High Performance Amplifiers, constructed using the New JRC Planar epitaxial process. They are intended for a wide range of analog applications where board space or weight are important. High common mode voltage range and absence of "latch-up" make the NJM1458 ideal for use as voltage followers. The high gain and wide range of operating voltage provides superior performance in integrator, summing amplifier and general feedback applications.

The NJM1458 is short-circuit protected and require no external components for frequency compensation. The internal 6 dB/octave roll-off insures stability in closed loop applications. For single amplifier performance, see the NJM741 data sheet.

■ PACKAGE OUTLINE



NJM1458D

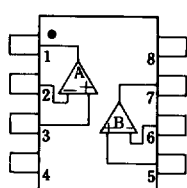


NJM1458M

■ FEATURES

- Operating Voltage (+3V ~ +18V)
- Output Short-Circuit Protection
- Package Outline DIP8, DMP8
- Bipolar Technology

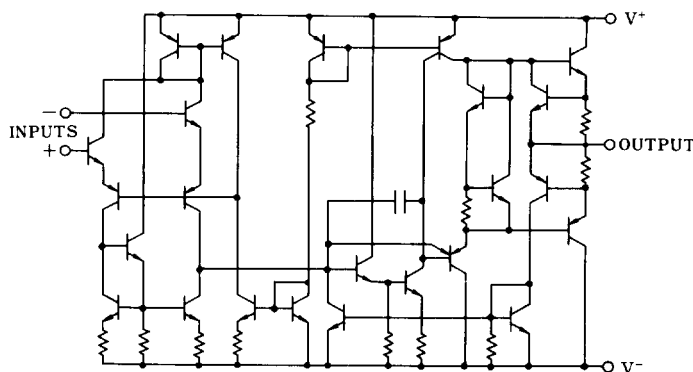
■ PIN CONFIGURATION

NJM1458D
NJM1458M

PIN FUNCTION

1. A OUTPUT
2. A-INPUT
3. A+INPUT
4. V⁻
5. B+INPUT
6. B-INPUT
7. B OUTPUT
8. V⁺

■ EQUIVALENT CIRCUIT





■ ABSOLUTE MAXIMUM RATINGS

(Ta=25°C)

PARAMETER	SYMBOL	RATINGS	UNIT
Supply Voltage	V ⁺ /V ⁻	±18	V
Input Voltage	V _i	±15	V
Differential Input Voltage	V _{ID}	±30	V
Power Dissipation	P _D	(DIP8) 500	mW
		(DMP8) 300	mW
Operating Temperature Range	T _{opr}	-20~+75	°C
Storage Temperature Range	T _{stg}	-40~+125	°C

(note) For supply voltage less than ±15V, the absolute maximum input voltage is equal to the supply voltage.

■ ELECTRICAL CHARACTERISTICS

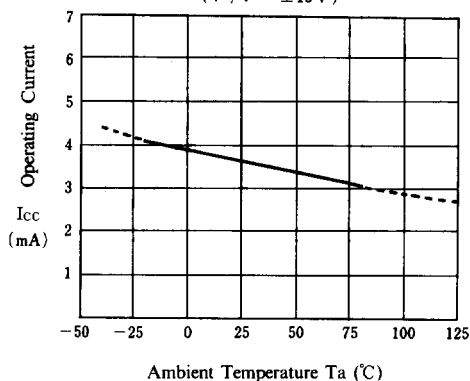
(Ta=25°C, V⁺/V⁻=±15V)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Input Offset Voltage	V _{IO}	R _S ≤10kΩ	—	2.0	6.0	mV
Input Offset Current	I _{IO}		—	5	200	nA
Input Bias Current	I _B		—	30	500	nA
Input Resistance	R _{IN}		0.3	1.0	—	MΩ
Large-signal Voltage Gain	A _V	R _L ≥2kΩ, V _O =±10V	86	106	—	dB
Maximum Output Voltage Swing I	V _{OM1}	R _L ≥10kΩ	±12	±14	—	V
Maximum Output Voltage Swing II	V _{OM2}	R _L ≥2kΩ	±10	±13	—	V
Input Common Mode Voltage Range	V _{ICM}		±12	±13	—	V
Common Mode Rejection Ratio	CMR	R _S ≤10kΩ	70	90	—	dB
Supply Voltage Rejection Ratio	SVR	R _S ≤10kΩ	76.5	90	—	dB
Operating Current	I _{CC}		—	3.3	5.7	mA
Slew Rate	SR	R _L ≥2kΩ, A _V =1	—	0.5	—	V/μs
Channel Separation Ratio	CS	f=1kHz	—	98	—	dB

■ TYPICAL CHARACTERISTICS

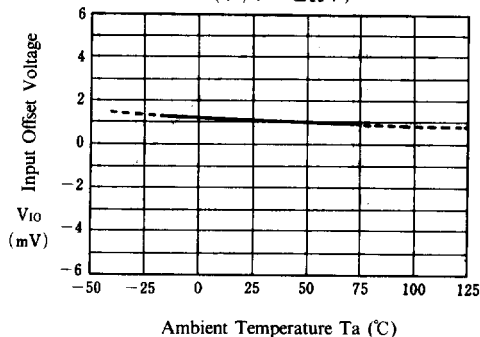
Operating Current vs. Temperature

($V^+/V^- = \pm 15\text{ V}$)



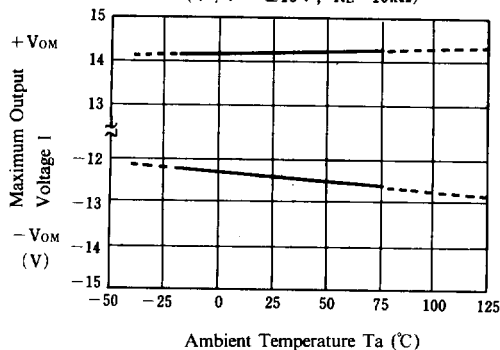
Input Offset Voltage vs. Temperature

($V^+/V^- = \pm 15\text{ V}$)



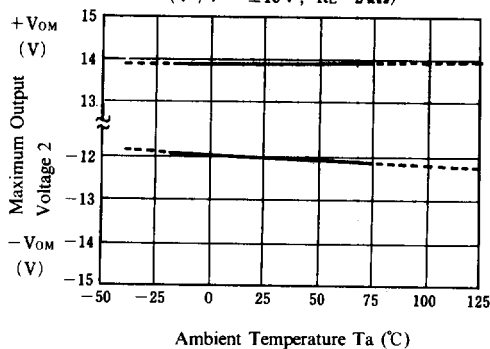
Maximum Output Voltage 1 vs. Temperature

($V^+/V^- = \pm 15\text{ V}$, $R_L = 10\text{ k}\Omega$)



Maximum Output Voltage 2 vs. Temperature

($V^+/V^- = \pm 15\text{ V}$, $R_L = 2\text{ k}\Omega$)

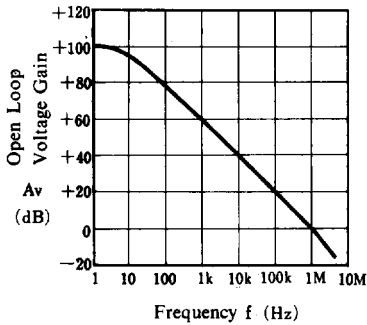




TYPICAL CHARACTERISTICS

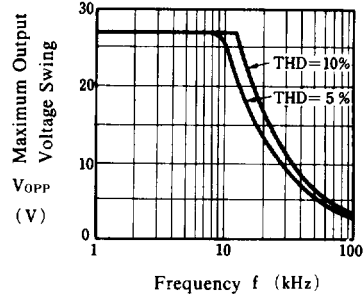
Open Loop Frequency Response

($V^+/V^- = \pm 15V$, $T_a = 25^\circ C$)



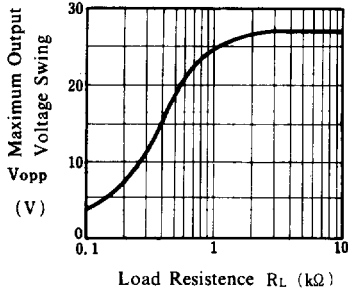
Maximum Output Voltage Swing vs. Frequency

($V^+/V^- = \pm 15V$, $T_a = 25^\circ C$)



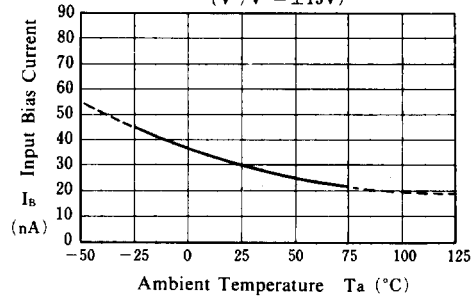
Maximum Output Voltage Swing vs. Load Resistance

($V^+/V^- = \pm 15V$, $T_a = 25^\circ C$)



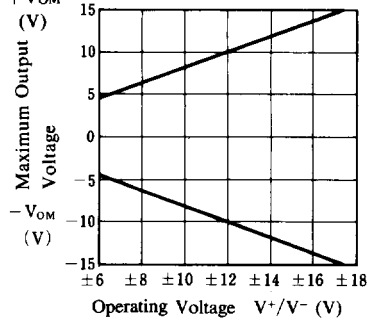
Input Bias Current vs. Temperature

($V^+/V^- = \pm 15V$)



Maximum Output Voltage Swing vs. Operating Voltage

($R_L = 2k\Omega$, $T_a = 25^\circ C$)



Input Bias Current vs. Operating Voltage

($R_s = 10k\Omega$, $T_a = 25^\circ C$)

